

****NOT TO EXCEED GATE POWER RATINGS**

CHARACTERISTICS

C11 SERIES

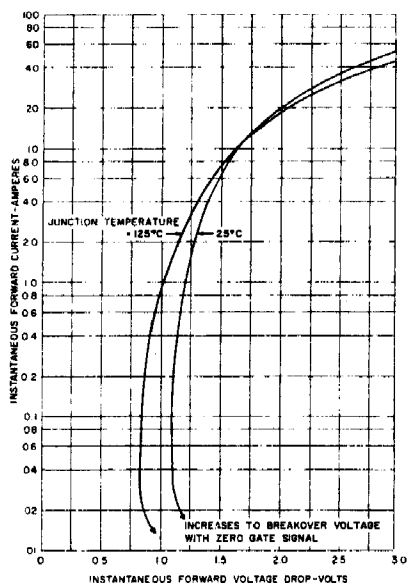
2N1770-78

2N2619

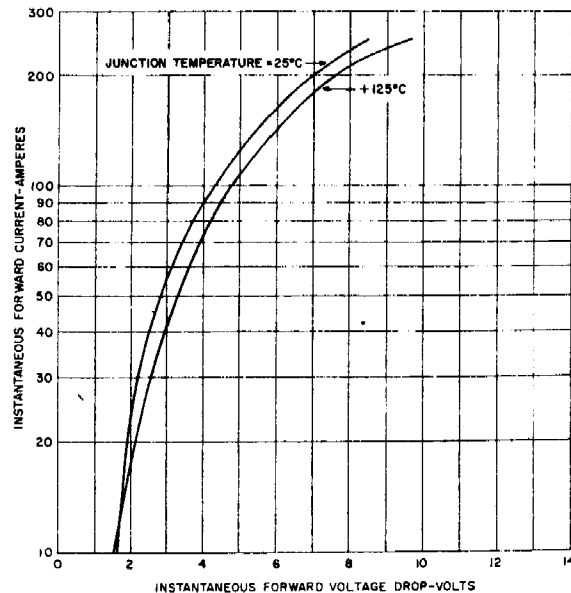
Test	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Peak Reverse and Forward Blocking Current†	i_R and i_S					$T_J = 125^\circ\text{C}$, Gate Open $V_{AC} = V_{CA} = 25$ Volts Peak
C11U (2N1770)		—	4.5	9.0	ma	50
C11F (2N1771)		—	4.5	9.0	ma	100
C11A (2N1772)		—	4.5	9.0	ma	150
C11G (2N1773)		—	4.0	8.0	ma	200
C11B (2N1774)		—	3.0	6.0	ma	250
C11H (2N1775)		—	2.5	5.0	ma	300
C11C (2N1776)		—	1.5	4.0	ma	400
C11D (2N1777)		—	1.0	2.0	ma	500
C11E (2N1778)		—	1.0	2.0	ma	600
C11M (2N2619)		—	1.0	2.0	ma	
Full Cycle Avg. Reverse and Forward Blocking Current†	$I_{R(AV)}$ and $I_{S(AV)}$					$T_J = 60^\circ\text{C}$, $I_o = 4.7\text{A}$, half sine wave 180° Conduction Angle $V_{AC} = V_{CA} = 25$ Volts Peak
C11U (2N1770)		—	2.3	4.5*	mA dc	50
C11F (2N1771)		—	2.3	4.5*	mA dc	100
C11A (2N1772)		—	2.3	4.5*	mA dc	150
C11G (2N1773)		—	2.0	4.0*	mA dc	200
C11B (2N1774)		—	1.5	3.0*	mA dc	250
C11H (2N1775)		—	1.3	2.5*	mA dc	300
C11C (2N1776)		—	0.8	2.0*	mA dc	400
C11D (2N1777)		—	0.5	1.0*	mA dc	500
C11E (2N1778)		—	0.5	1.0*	mA dc	600
C11M (2N2619)		—	0.5	1.0*	mA dc	
Gate Current to Fire	I_{GF}					$V_{AC} = 12\text{Vdc}$, $T_J = 25^\circ\text{C}$, $R_L = 250$ ohms
		—	10	15	mA dc	$V_{AC} = 12\text{Vdc}$, $T_J = -65^\circ\text{C}$, $R_L = 250$ ohms
		—	20	30*	mA dc	$V_{AC} = 12\text{Vdc}$, $T_J = 125^\circ\text{C}$, $R_L = 250$ ohms
		—	4	8	mA dc	
Gate Voltage to Fire	V_{GF}					$V_{AC} = 12\text{Vdc}$, $T_J = -65^\circ$ to $+125^\circ\text{C}$, $R_L = 250$ ohms
		—	1.3	2.0*	Vdc	$V_{AC} = \text{Rated}$, $T_J = 125^\circ\text{C}$, $R_L = 250$ ohms
		—	0.3*	0.7	Vdc	
Peak Forward Voltage Drop	V_F					$T_J = 25^\circ\text{C}$, $i_F = 15\text{a}$ (single sinusoidal pulse, 4 ms wide)
		—	1.6	1.85	v	
Holding Current	I_H					Anode Supply = 6 Vdc, $T_J = 25^\circ\text{C}$
		—	8.0	—	mA dc	
Turn-on Time	$t_d + t_r$					$T_J = 25^\circ\text{C}$, $i_F = 10\text{a}$, $V_{AC} = \text{Rated}$ Gate Supply: 7 volt open circuit, 20 ohm, 0.1 μsec max. rise time.
		—	1.0	—	μsec	
Turn-off Time	t_{off}					$T_J = 125^\circ\text{C}$, $i_F = 5\text{a}$, $i_R = 5\text{a}$ V_{AC} (Reapplied) = Rated. Rate of Rise of Reapplied Forward Blocking Voltage = 20 volts per microsecond maximum.
		—	15	—	μsec	
Thermal Resistance	θ_{JA}					Junction to Case.
		—	1.5	3.1	$^\circ\text{C}/\text{Watt}$	

†Values apply for zero or negative gate voltage. Maximum case to ambient thermal resistance for which maximum PRV ratings apply = 18°C per watt.

*Indicates data included on JEDEC type number registration.



1. MAXIMUM FORWARD CHARACTERISTICS
CONDUCTING STATE



2. MAXIMUM FORWARD CHARACTERISTICS
HIGH CURRENT LEVEL — CONDUCTING STATE